Darlington Transistor

NPN Silicon

Features

• These are Pb-Free Devices*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CES}	60	Vdc
Emitter-Base Voltage	V _{EBO}	10	Vdc
Collector Current - Continuous	I _C	500	mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _D	625 5.0	mW mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C

THERMAL CHARACTERISTICS

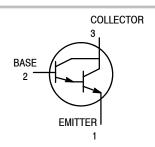
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	°C/W

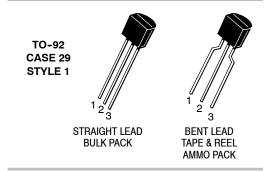
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



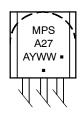
ON Semiconductor®

http://onsemi.com





MARKING DIAGRAM



= Assembly Location

= Year WW = Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]		
MPSA27G	TO-92 (Pb-Free)	5000 Units/Bulk		
MPSA27RLRA	TO-92	2000/Tape & Reel		
MPSA27RLRAG	TO-92 (Pb-Free)	2000/Tape & Reel		

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

* * * *	•				
Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	·				•
Collector-Emitter Breakdown Voltage ($I_C = 100 \mu Adc$, $V_{BE} = 0$)	V _{(BR)CES}	60	-	-	Vdc
Collector-Base Breakdown Voltage ($I_C = 100 \mu Adc$, $I_E = 0$)	V _(BR) CBO	60	-	-	Vdc
Collector Cutoff Current $ (V_{CB} = 30 \text{ V}, I_E = 0) $ $ (V_{CB} = 40 \text{ V}, I_E = 0) $ $ (V_{CB} = 50 \text{ V}, I_E = 0) $	І _{СВО}	-	-	100	nAdc
Collector Cutoff Current $(V_{CE} = 30 \text{ V}, V_{BE} = 0)$ $(V_{CE} = 40 \text{ V}, V_{BE} = 0)$ $(V_{CE} = 50 \text{ V}, V_{BE} = 0)$	loes	-	-	500	nAdc
Emitter Cutoff Current (V _{EB} = 10 Vdc)	I _{EBO}	-	-	100	nAdc
ON CHARACTERISTICS (Note 1)	•	•		•	•
DC Current Gain $(I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ V})$ $(I_C = 100 \text{ mA}, V_{CE} = 5.0 \text{ V})$	h _{FE}	10,000 10,000			-
Collector-Emitter Saturation Voltage (I _C = 100 mA, I _B = 0.1 mAdc)	V _{CE(sat)}	-	-	1.5	Vdc
Base-Emitter On Voltage (I _C = 100 mA, V _{CE} = 5.0 Vdc)	V _{BE(on)}	-	-	2.0	Vdc
SMALL-SIGNAL CHARACTERISTICS	•	-		•	•
Small Signal Current Gain ($I_C = 10 \text{ mA}$, $V_{CE} = 5.0 \text{ V}$, $f = 100 \text{ MHz}$)	h _{fe}	1.25	2.4	-	-

Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%.

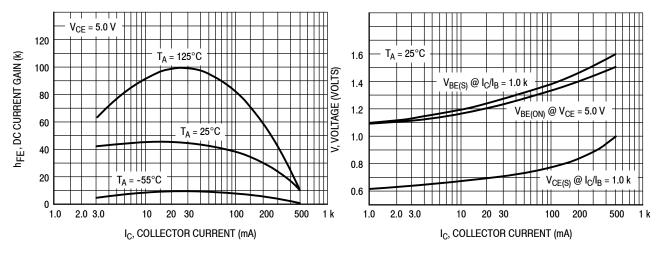


Figure 1. DC Current Gain

Figure 2. "ON" Voltages

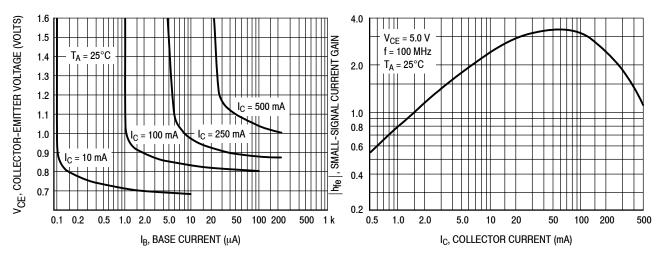


Figure 3. Collector Saturation Region

Figure 4. High Frequency Current Gain

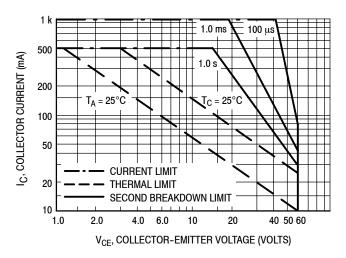
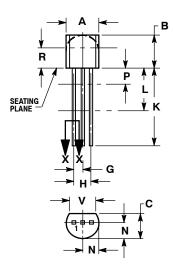


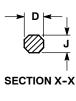
Figure 5. Active Region - Safe Operating Area

PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 ISSUE AM



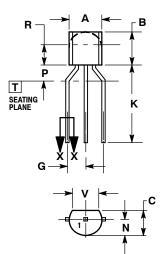
STRAIGHT LEAD **BULK PACK**



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- CONTOUR OF PACKAGE BEYOND DIMENSION R
- IS UNCONTROLLED.
 LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	ETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
P		0.100		2.54
R	0.115		2.93	
٧	0.135		3.43	



BENT LEAD TAPE & REEL AMMO PACK



NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: MILLIMETERS.
 CONTOUR OF PACKAGE BEYOND
 DIMENSION R IS UNCONTROLLED.
 LEAD DIMENSION IS UNCONTROLLED IN P
- AND BEYOND DIMENSION K MINIMUM

	MILLIMETERS		
DIM	MIN	MAX	
Α	4.45	5.20	
В	4.32	5.33	
С	3.18	4.19	
D	0.40	0.54	
G	2.40	2.80	
J	0.39	0.50	
K	12.70		
N	2.04	2.66	
P	1.50	4.00	
R	2.93		
٧	3.43		

STYLE 1: PIN 1. EMITTER

BASE

COLLECTOR

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